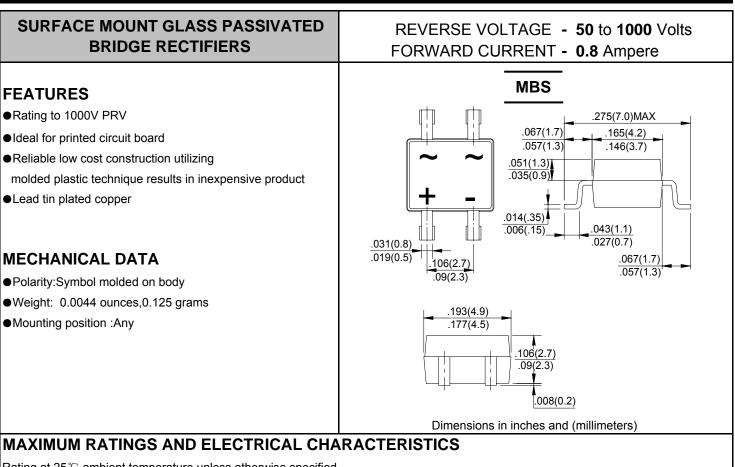


B05S thru B10S



Rating at 25 $^\circ\!\!\!\!^\circ\mathbb{C}$ ambient temperature unless otherwise specified.

Single phase, half wave ,60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

SVMDOL							1	1
SYMBOL	B05S	B1S	B2S	B4S	B6S	B8S	B10S	UNIT
Vrrm	50	100	200	400	600	800	1000	V
Vrms	35	70	140	280	420	560	700	V
VDC	50	100	200	400	600	800	1000	V
l(AV)	0.8							А
IFSM	30							A
VF	1.1						V	
lĸ	5.0 500							μA
CJ	15							pF
Rejc	75							℃/W
TJ	-55 to +150							°C
Тѕтс	-55 to +150							°C
	VRRM VRMS VDC I(AV) IFSM VF IR CJ R0JC TJ	VRRM 50 VRMS 35 VDC 50 I(AV)	VRRM 50 100 VRMS 35 70 VDC 50 100 I(AV)	VRRM 50 100 200 VRMS 35 70 140 VDC 50 100 200 I(AV)	VRRM 50 100 200 400 VRMS 35 70 140 280 VDC 50 100 200 400 I(AV) 50 100 200 400 I(AV) 0.8 30 30 VF 1.1 30 500 500 VF 1.1 5.0 500 500 CJ 15 75 75 75 TJ -55 to +150 -55 to +150 50	VRRM 50 100 200 400 600 VRMS 35 70 140 280 420 VDC 50 100 200 400 600 I(AV) 50 100 200 400 600 I(AV) 0.8 30 0.8 30 0.8 VF 1.1 30 1.1 1.1 1.1 IR 5.0 50 50	VRRM 50 100 200 400 600 800 VRMS 35 70 140 280 420 560 VDC 50 100 200 400 600 800 VDC 50 100 200 400 600 800 I(AV) 0.8 0.8 0.8 0.8 0.8 0.8 IFSM 30 0.8 30 0.8 0.8 0.8 0.8 VF 1.1 1	VRRM 50 100 200 400 600 800 1000 VRMS 35 70 140 280 420 560 700 VDC 50 100 200 400 600 800 1000 VDC 50 100 200 400 600 800 1000 I(AV) 0.8 0.8 30 1000 1000 1000 1000 I(AV) 30 IFSM 30 .

NOTES:1.Mounted on P.C. board.

2.Measured at1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance junction to case

RATING AND CHARACTERTIC CURVES B05S thru B10S

